INTERNATIONAL RECTIFIER IOR

60HFU... SERIES

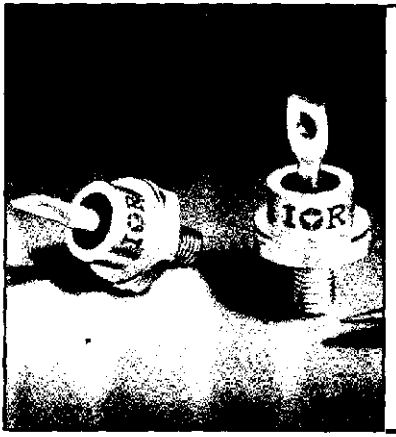
SUPER FAST RECTIFIER DIODE 60 Amp 60ns

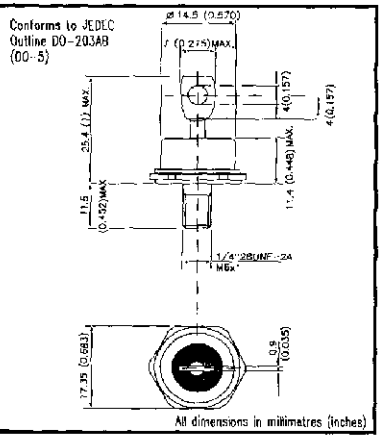
Major ratings and characteristics

		60HFU	Units
$I_{F(AVG)}$		60	A
T_c		82	°C
I_{RMS}		94	A
I_{FSM}	@10ms	830	A
I_{FSM}	@8.3ms	870	A
V_{RRM}		100 to 600	V
T_j		-40 to 125	°C

Description and Features

- Very low reverse recovery time
- Reduced switching losses
- Soft recovery characteristics
- High surge current capability
- No voltage derating up to 150°C
- Stud cathode and stud anode versions
- Designed for switching applications:
  Free wheeling diode in converters and control circuits
  Rectifier in S.M.P.S.





ELECTRICAL SPECIFICATIONS

Forward Conduction

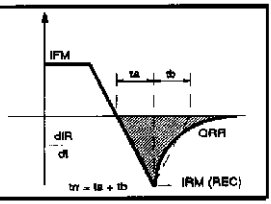
	Parameters	Value	Units	Conditions
$I_{F(AV)}$	Maximum average forward current	60	A	180° conduction, half sine cond @ Case temperature = 82°C
		67	A	180° conduction, rect cond @ Case temperature = 82°C
I_{RMS}	Maximum RMS current	94	A	
I_{FSM}	Maximum peak, one-cycle non-repetitive forward current initial $T_J = T_J$ max.	830	A	t = 10ms No voltage reapplied
		870	A	t = 8.3ms
		700	A	t = 10ms 100% V_{RRM} reapplied
		730	A	t = 8.3ms
I^2t	Maximum I^2t for fusing initial $T_J = T_J$ max.	3460	A^2s	t = 10ms No voltage reapplied
		3160	A^2s	t = 8.3ms
		2450	A^2s	t = 10ms 100% V_{RRM} reapplied
		2240	A^2s	t = 8.3ms
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	34800	$A^2\sqrt{s}$	t = 0 to 10ms, no voltage reapplied
$V_{F(TO)}$	Maximum value of threshold voltage	1.08	V	T_J = 125°C
r_t	Maximum value of forward slope resistance	3.40	mΩ	T_J = 125°C
V_{FM}	Maximum forward voltage drop	1.50	V	I_{FM} = 60 Apk T_J = 25 °C
		1.30	V	I_{FM} = 60 Apk T_J = 125 °C

Thermal and Mechanical Specifications

T_J	Junction temperature range	-40 to 125	°C	
T_{stg}	Storage temperature range	-40 to 150	°C	
R_{thJC}	Maximum thermal resistance junction to case	0.36	K/W	DC operation per junction
R_{thCS}	Maximum thermal resistance, case to heatsink	0.25	K/W	Mounting surface , smooth and greased
T	Mounting torque, base to heatsink ±10%	2.5	Nm	A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound
wt	Approximate weight	25	g	

Recovery Characteristics

	Parameters	Typ.	Max.	Units	Conditions
t_{rr}	Recovery time	60	80	ns	T_J = 25 °C IF = 1A, dIF/dt = -100 A/µs, Vr = -30V
Q_{rr}	Recovered charge	250	300	nC	T_J = 25 °C IF = 1A, dIF/dt = -100 A/µs, Vr = - 30V



Voltage ratings ($T_J = T_J$ max.)

Type number	V_{RRM} , maximum repetitive peak reverse voltage	V_{RSM} , maximum non-repetitive peak reverse voltage	I_{RRM} Max @ 100°C	I_{RRM} Max @ 150°C	I_{RRM} Typ. @ 25°C
	V	V	mA	mA	µA
60HFU(R)-100	100	110	5	15	50
60HFU(R)-200	200	220	5	15	50
60HFU(R)-300	300	330	5	15	50
60HFU(R)-400	400	440	5	15	50
60HFU(R)-500	500	550	5	25	50
60HFU(R)-600	600	660	5	25	50

ΔR Conduction (per junction)

(The following table shows the increment of thermal resistance $R th_{J-C}$ when devices operate at different conduction angles than DC.)

Conduction angle	Sinusoidal Conduction	Rectangular Conduction	Units	Conditions
180°	0.06	0.05	K/W	
120°	0.08	0.09	K/W	
90°	0.10	0.12	K/W	
60°	0.15	0.16	K/W	
30°	0.24	0.24	K/W	

Fig.1 - Maximum Forward Energy Loss Per Pulse Characteristics

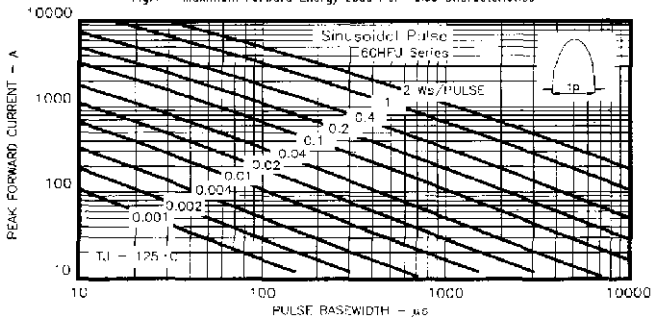
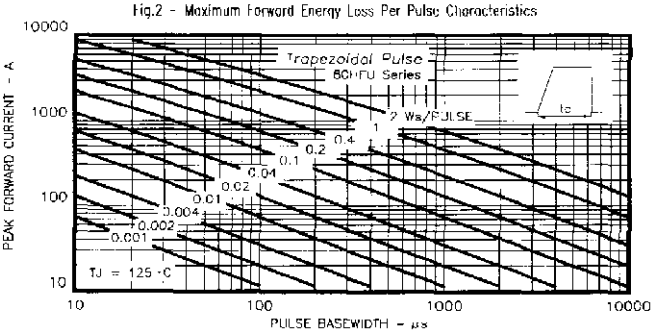
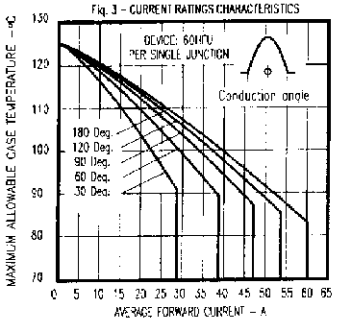
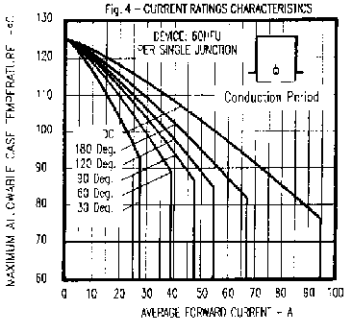
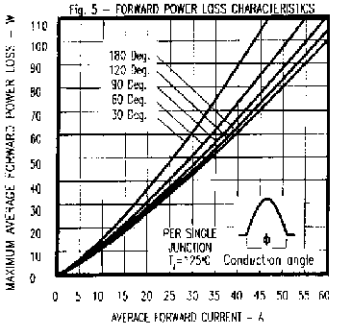


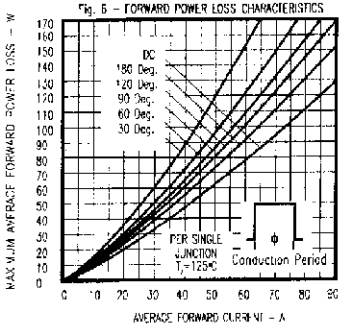
Fig.2 - Maximum Forward Energy Loss Per Pulse Characteristics

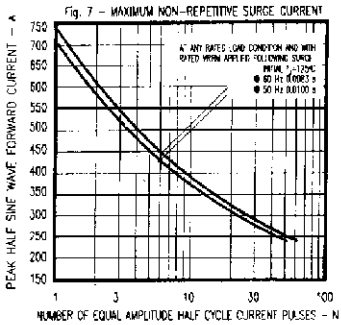












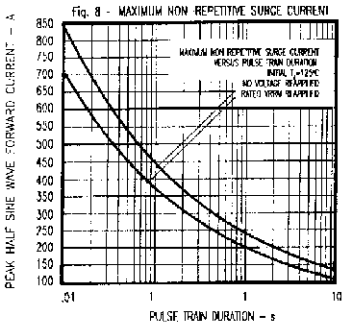


Fig. 9 – FORWARD VOLTAGE DROP CHARACTERISTICS

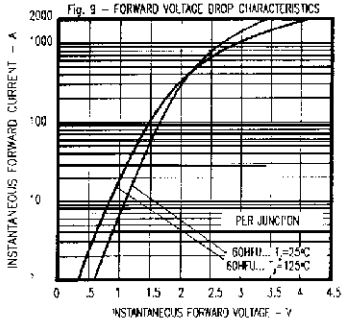


Fig. 10 – THERMAL IMPEDANCE Z_{thjc} CHARACTERISTICS

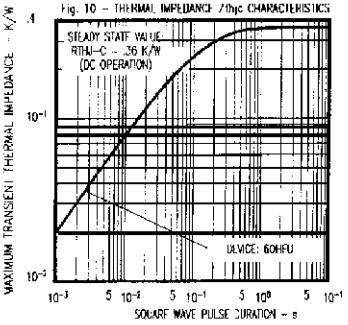


Fig. 11– RECOVERY TIME CHARACTERISTICS

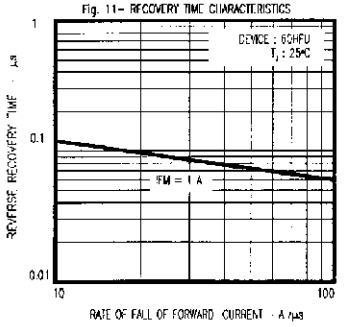
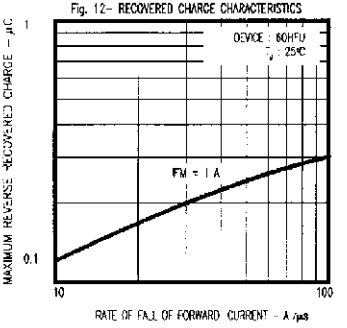


Fig. 12– RECOVERED CHARGE CHARACTERISTICS



indemnify Vishay for any damages resulting from such improper use or sale.